

Features

1) Low on-resistance

2) Fast switching speed

3) Fast reverse recovery

6) Pb-free lead plating ; RoHS compliant

4) Easy to parallel

5) Simple to drive

ApplicationSolar inverters

DC/DC converters

Induction heating

Motor drives

· Switch mode power supplies

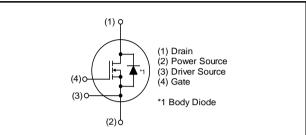
SCT4062KR N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	62mΩ
^{*1}	26A
P _D	115W

Outline



Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Turne	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C15
	Marking	SCT4062KR

•Absolute maximum ratings (T_{vj} = 25°C unless otherwise specified.)

Parameter		Symbol	Value	Unit	
Drain - source voltage		V _{DSS}	1200	V	
Continuous drain		$T_c = 25^{\circ}C$	ı ı *1	26	А
and source current	$V_{GS} = V_{GS_{on}}$	$T_c = 100^{\circ}C$	Ι _D , Ι _S ^{*1}	18	А
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	I _{D,pulse} *2	52	А
Body diode pulsed forwa	ard current	T _c = 25°C	*1,*3 I _{S,pulse}	26	А
Body diode surge forward current V _{GS}		$V_{GS} = 0 V$	^{*1,*4} I _{S,pulse}	52	А
Gate - source voltage (DC)		$V_{GSS_{DC}}$	-4 to +21	V	
Gate - source surge vol	tage (t _{surge} < 300)ns)	V_{GSS_surge} *5	-4 to +23	V
Recommended turn-on	gate - source dr	ive voltage	V _{GS_on} *6	+15 to +18	V
Recommended turn-off gate - source drive voltage		V _{GS_off}	0	V	
Virtual junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-40 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

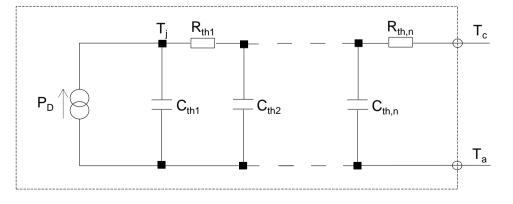
Deremeter	Cumphal	Conditions	Values			Linit	
Parameter	Symbol Conditions -		Min.	Тур.	Max.	Unit	
Drain - Source breakdown	V	$V_{GS} = 0 V, I_{D} = 5.3 mA$				V	
voltage	v (BR)DSS	$T_{vj} = 25^{\circ}C$	1200	-	-	V	
		$V_{GS} = 0 V, V_{DS} = 1200V$					
Zero Gate voltage Drain current	I _{DSS}	T _{vj} = 25°C	-	1	80	μA	
		T _{vj} = 150°C	-	10	-		
Gate - Source leakage current	I _{GSS+}	V_{GS} = +21V , V_{DS} = 0V	-	-	100	nA	
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}{}^{*7}$	$V_{DS} = 10V, I_{D} = 6.45mA$	2.8	-	4.8	V	
		$V_{GS} = 18V, I_{D} = 12A$					
Static Drain - Source on - state resistance	R _{DS(on)} *8	T _{vj} = 25°C	-	62	81	mΩ	
		T _{vj} = 150°C	-	124	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	4	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
Faranielei	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R_{thJC}^{*9}	-	0.98	1.3	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	8.4 ×10 ⁻²		C _{th1}	5.3 ×10 ⁻⁴	
R _{th2}	4.7 ×10 ⁻¹	K/W	C _{th2}	2.4 ×10 ⁻³	Ws/K
R _{th3}	4.2 ×10 ⁻¹		C _{th3}	4.3 ×10 ⁻²	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Deremeter	Curren al	nbol Conditions -		Values			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Transconductance	g _{fs} *8	$V_{DS} = 10V, I_{D} = 12A$	-	6.5	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	1498	-		
Output capacitance	C_{oss}	V _{DS} = 800V	-	45	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	3	-		
Effective output capacitance, energy related	$C_{o(er)}$	V _{GS} = 0V V _{DS} = 0V to 800V	-	54	-	pF	
Total Gate charge	Q _g *8	V _{DS} = 800V I _D = 12A	-	64	-		
Gate - Source charge	Q _{gs} *8	$V_{GS} = 18V$	-	14	-	nC	
Gate - Drain charge	Q _{gd} *8	See Fig. 1-1, 1-2.	-	17	-		
Turn - on delay time	t _{d(on)} *8	$V_{DS} = 800V$ $I_{D} = 12A$	-	4.4	-		
Rise time	t _r *8	V _{GS} = +18V / 0V	-	11	-	ns	
Turn - off delay time	t _{d(off)} *8	$R_G = 0\Omega, L = 250\mu H$ E _{on} includes diode	-	22	-	115	
Fall time	t _f *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	10	-		
Turn - on switching loss	E _{on} *8	See Fig. 2-1, 2-2, 2-3.	-	132	-		
Turn - off switching loss	E _{off} *8		-	6	-	μJ	



•Body diode electrical characteristics (Source-Drain) (T_{vi} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward voltage	V_{SD} *8	$V_{GS} = 0V, I_S = 12A$	-	3.3	-	V
Reverse recovery time	t _{rr} *8	$I_F = 12A$ $V_R = 800V$	-	8.1	-	ns
Reverse recovery charge	Q _{rr} *8	di/dt = 3800A/μs	-	105	-	nC
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	26	-	А

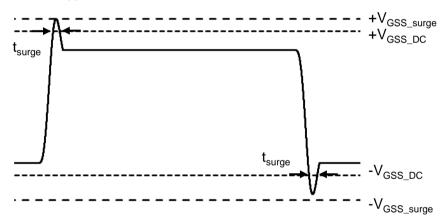
*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 Pulse width and duty cycle are limited by $T_{vj,max}$.

*3 Only for body-diode, Repititive pulse, PW \leq 1.5µs, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



Please note especially when using driver source that V_{GSS_surge} must be in the range of absolute maximum rating.

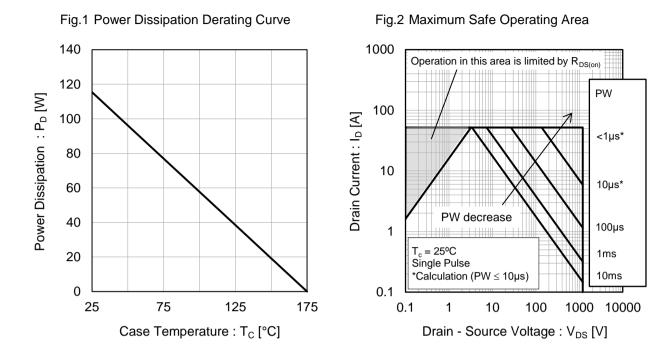
- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying $V_{GS} = 21V$ for 100ms.
- *8 Pulsed
- *9 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

 ${\tt URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf}$









Duty increase

 $T_c = 25^{\circ}C$

Fig.3 Typical Transient Thermal

Pulse Width : PW [s]

1E-6 1E-5 1E-4 1E-3 1E-2 1E-1 1E+0 1E+1

0.2

0.1 0.05

0.02 0.01

Single pulse

Transient Thermal Impedance :

0.01

0.001

0.0001



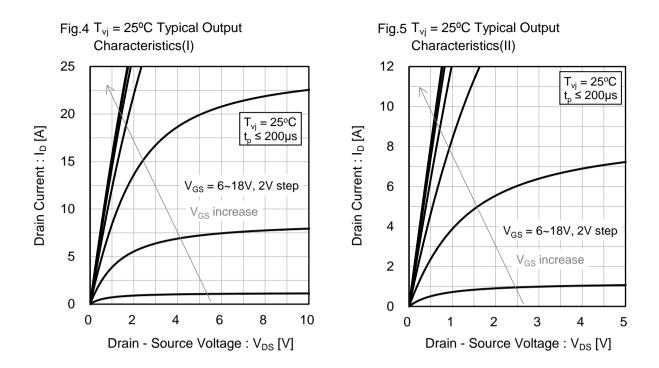
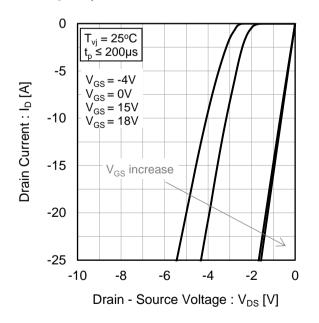
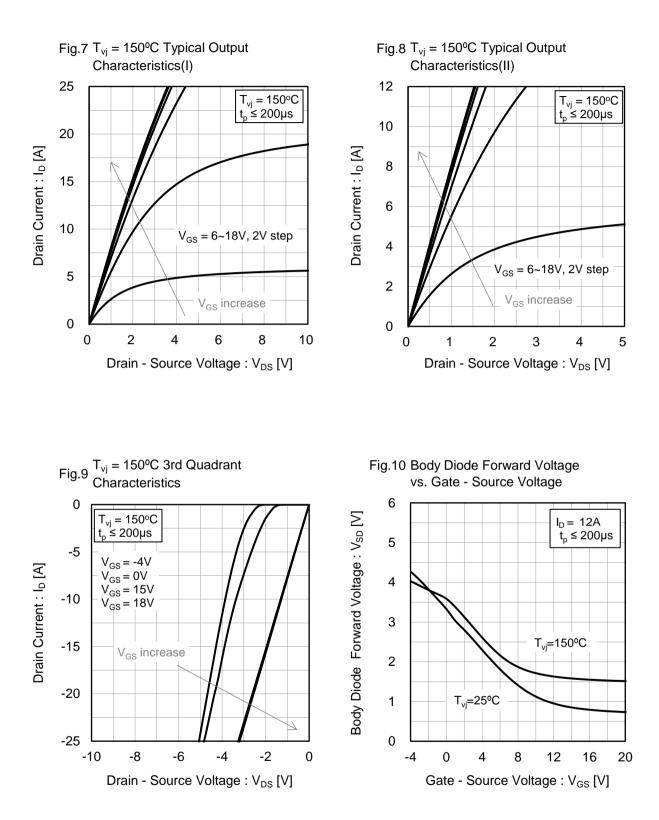


Fig.6 $T_{vj} = 25^{\circ}C$ 3rd Quadrant Characteristics



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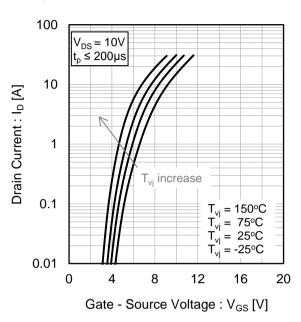
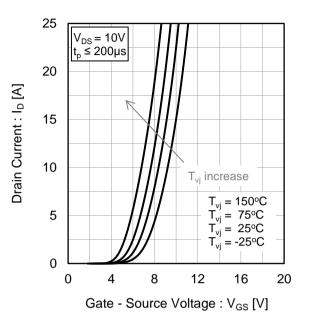


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



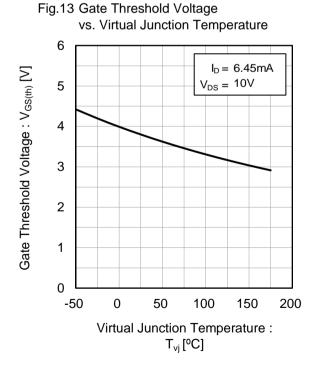
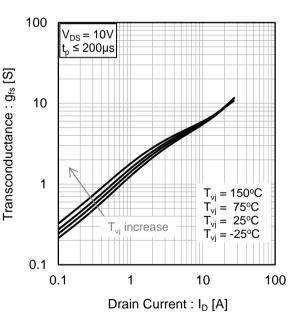
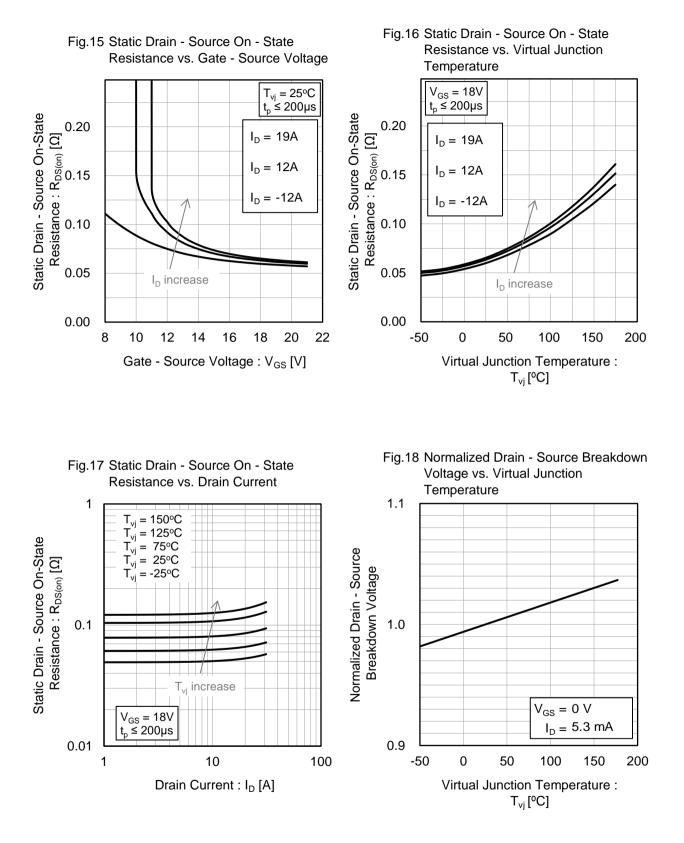


Fig.14 Transconductance vs. Drain Current









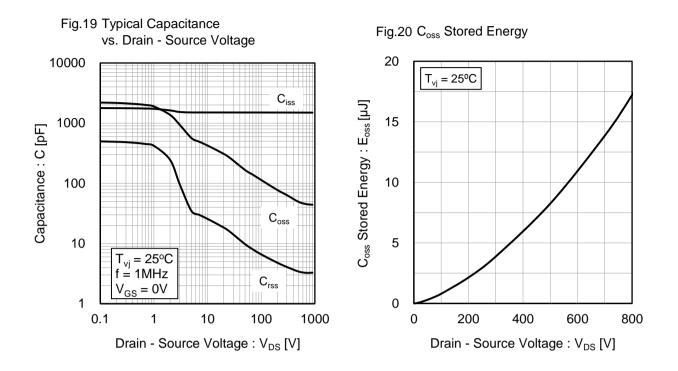
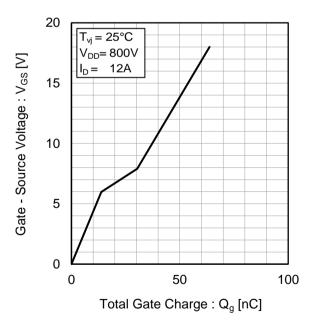
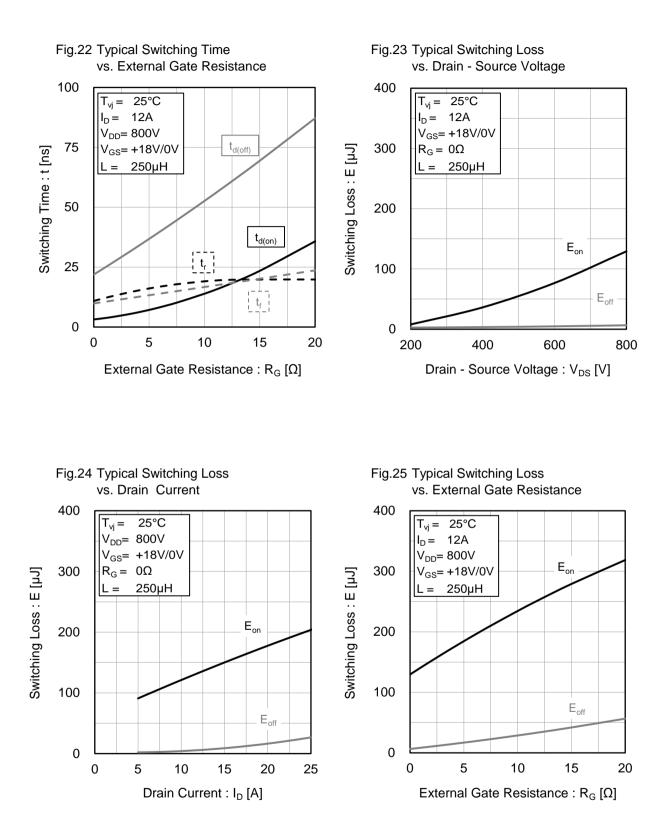


Fig.21 Dynamic Input Characteristics









Measurement circuits and waveforms



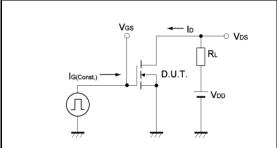


Fig.2-1 Switching Characteristics Measurement Circuit

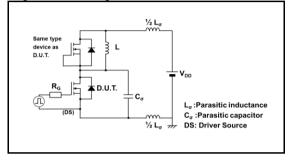


Fig.2-3 Waveforms for Switching Energy Loss

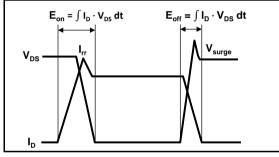


Fig.3-1 Reverse Recovery Time Measurement Circuit

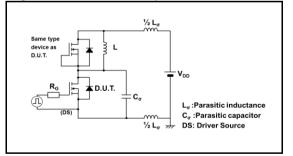


Fig.1-2 Gate Charge Waveform

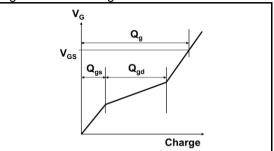


Fig.2-2 Waveforms for Switching Time

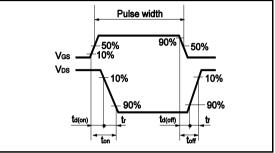
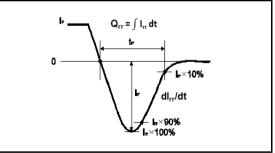
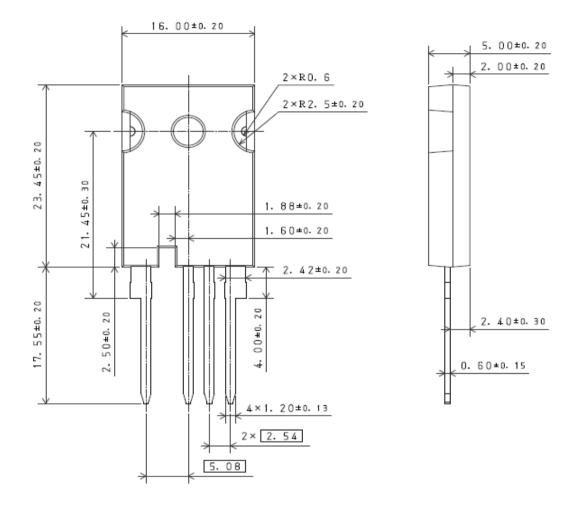


Fig.3-2 Reverse Recovery Waveform





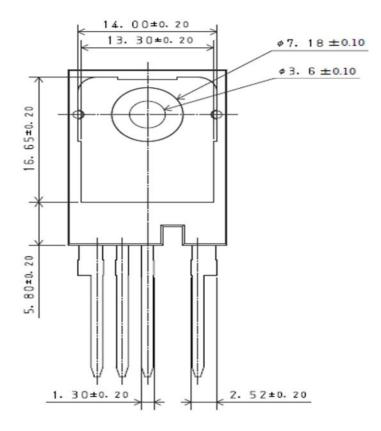
Package Dimensions



Unit: mm





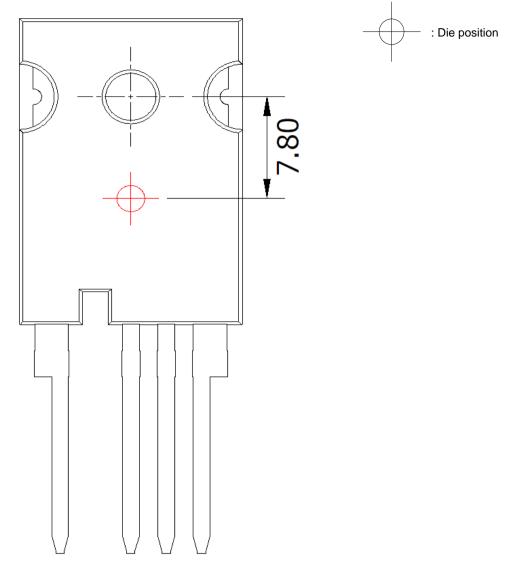


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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